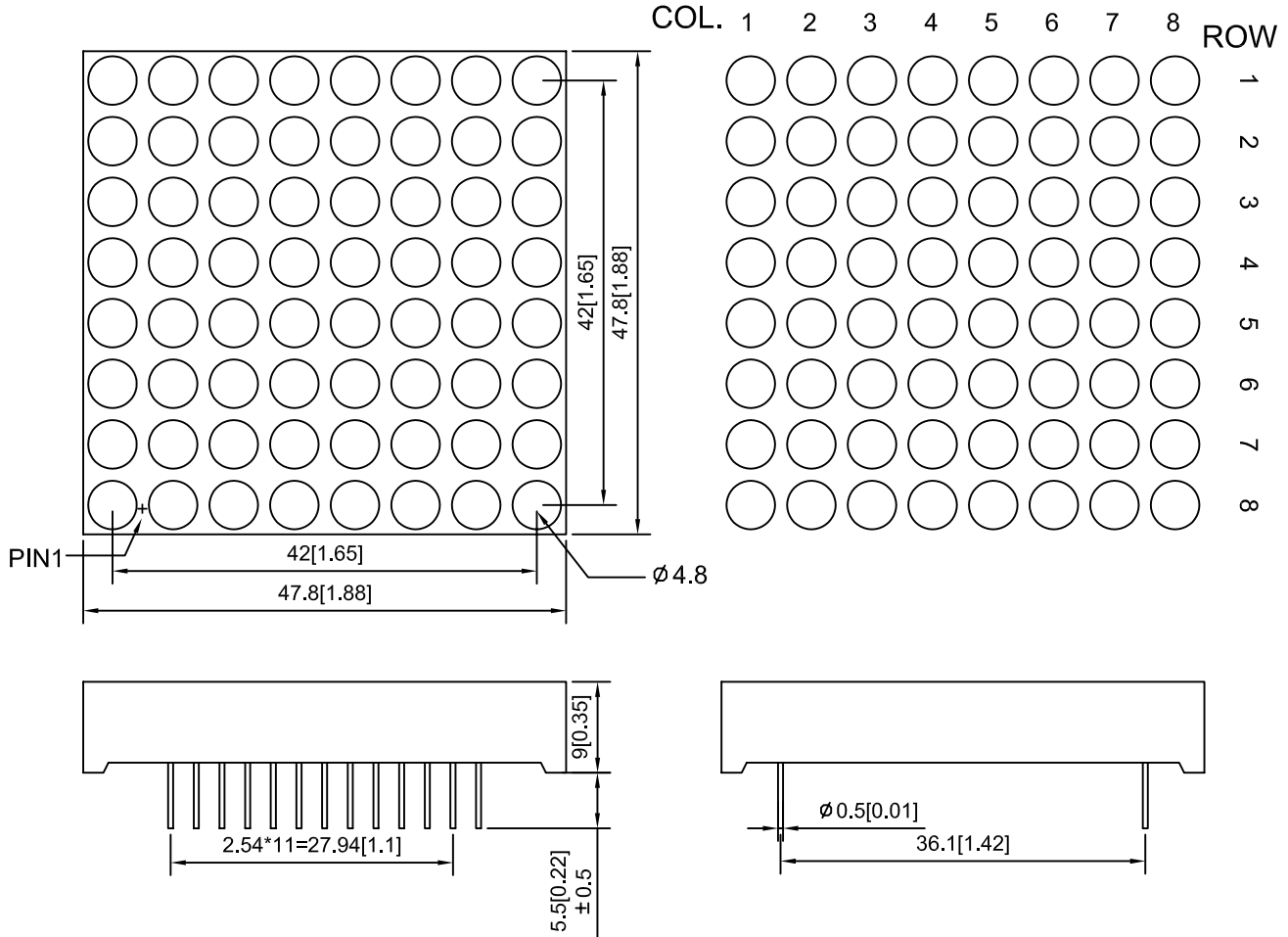


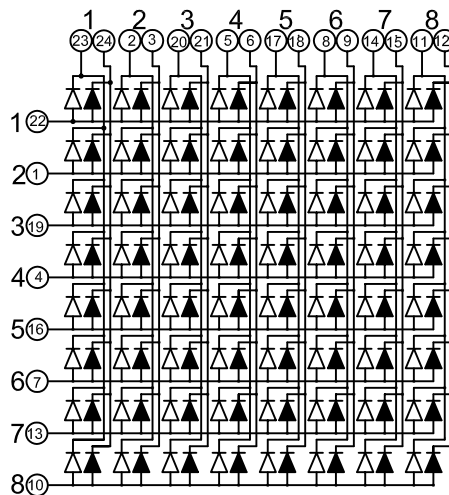


# GYXM-1988ASRG管对线错

## PACKAGE DIMENSIONS



## INTERNAL CIRCUIT DIAGRAM



### NOTES:

1. All Dimensions are in millimeters.
2. Tolerance is  $\pm 0.25\text{mm}$  unless otherwise noted

—▷ GREEN —▷ RED



## General Information

Part NO.	Chip Material	Emitting Color	Lens Type	Description
GYXM-1988ASRG	GaAlAs/GaAs	RED	water clear	Common Anode
	GaP	GREEN		

## Electrical/Optical Characteristics at Ta=25°C

Parameter	Symbol	Typ.	Max.	Unit	Conditions
Luminous Intensity	I <sub>v</sub>	12	—	mcd	I <sub>F</sub> =20mA
		13	—		
Peak Wavelength	λ <sub>P</sub>	—	—	nm	I <sub>F</sub> =20mA
		—	—		
Dominant Wavelength	λ <sub>D</sub>	645	—	nm	I <sub>F</sub> =20mA
		572	—		
Spectral Line Half-Width	Δλ	—	45	nm	I <sub>F</sub> =20mA
		—	—		
Forward Voltage	V <sub>F</sub>	1.85	1.95	V	I <sub>F</sub> =20mA
		2.20	2.30		
Reverse Current	I <sub>R</sub>	50	—	μA	V <sub>R</sub> =5V

## Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Maximum Rating	Unit
Power Dissipation	P <sub>d</sub>	65	mW
		75	
Forward Current	I <sub>F</sub>	20	mA
Peak Forward Current(1)	I <sub>F</sub> (Peak)	120	mA
		120	
Reverse Voltage	V <sub>R</sub>	5	V
Operating Temperature	T <sub>opr</sub>	-40° c+80° c	
Storage Temperature	T <sub>stg</sub>	-40° c+80° c	
Lead Solder Temperature(2)	T <sub>sol</sub>	260° c for 5 seconds	

## Notes:

- 1/10 duty cycle, 0.1ms pulse width.
- 2mm below package base.